Schottky Barrier Diode

NSR0230M2T5G, NSVR0230M2T5G

These Schottky barrier diodes are designed for high-speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand-held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Extremely Low Forward Voltage 0.325 V (max) @ I_F = 10 mA
- Low Reverse Current
- AEC Qualified and PPAP Capable
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- This is a Pb-Free Device*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	30	Vdc
Forward Current DC	I_F	200	mA
Forward Current Surge Peak (60 Hz, 1 cycle)	I_{FSM}	1.0	A
ESD Rating: Class 3B per Human Body Model Class C per Machine Model			

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

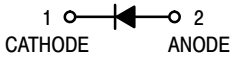
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T_A = 25 °C Derate above 25 °C	P_D	167 2.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	600	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	−55 to +125	°C

1. FR-5 Minimum Pad.

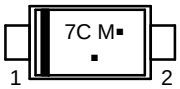
* For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

30 V SCHOTTKY BARRIER DIODE

SOD-723
CASE 509AA
PLASTIC



MARKING DIAGRAM



7C = Specific Device Code
M = Month Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NSR0230M2T5G	SOD-723 (Pb-Free)	2 mm Pitch 8,000/Tape & Reel
NSVR0230M2T5G	SOD-723 (Pb-Free)	2 mm Pitch 8,000/Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Leakage (V_R = 10 V) (V_R = 30 V)	I_R	 – –	 – –	 10 100	μA
Forward Voltage (I_F = 10 mA) (I_F = 200 mA)	V_F	 – –	 – –	 0.325 0.500	Vdc

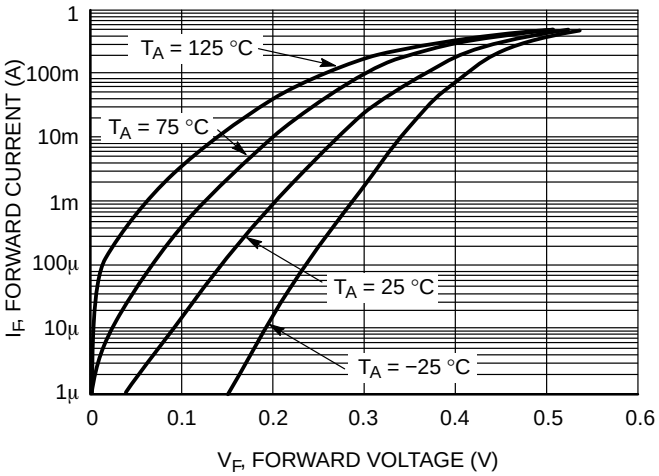


Figure 1. Forward Characteristics

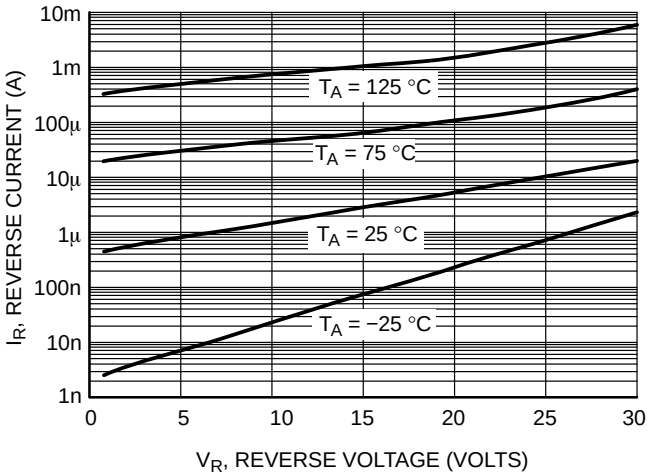


Figure 2. Reverse Characteristics

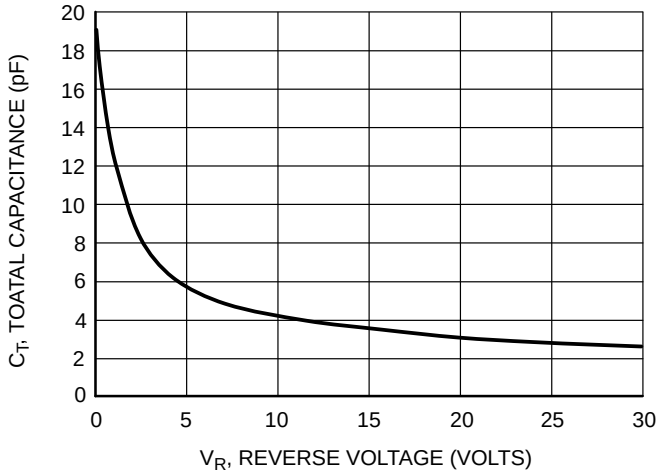
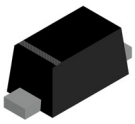


Figure 3. Total Capacitance

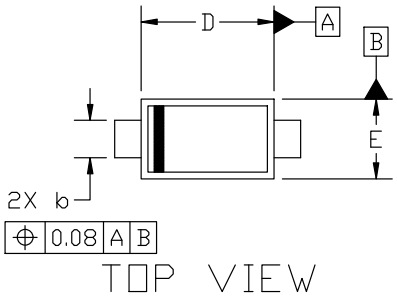
REVISION HISTORY

Revision	Description of Changes	Date
4	Rebranded the Data Sheet to **onsemi** format.	6/4/2025

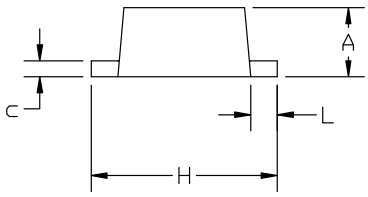


SOD−723, 2−LEAD, 1.00x0.60x0.52
CASE 509AA
ISSUE A

DATE 01 FEB 2024



TOP VIEW



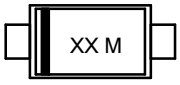
SIDE VIEW

NOTES:

1. DIMENSIONSING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETER.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

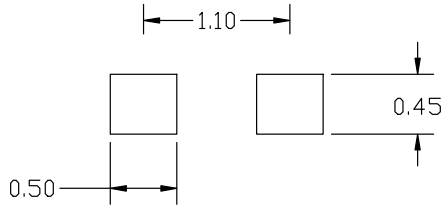
DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.49	0.52	0.55
b	0.25	0.28	0.32
c	0.08	0.12	0.15
D	0.95	1.00	1.05
E	0.55	0.60	0.65
H	1.35	1.40	1.45
L	0.15	0.20	0.25

GENERIC MARKING DIAGRAM*



XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED MOUNTING FOOTPRINT

*For additional formation on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	**98AON20359D**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.	
DESCRIPTION:	**SOD−723, 2−LEAD, 1.00x0.60x0.52**		**PAGE 1 OF 1**

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:
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